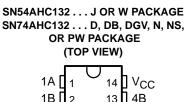
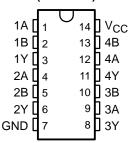
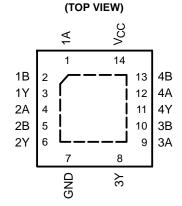
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- Operating Range 2-V to 5.5-V V<sub>CC</sub>
- Operation From Very Slow Input Transitions
- Temperature-Compensated Threshold Levels
- High Noise Immunity

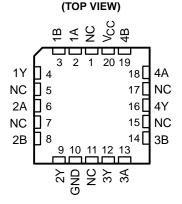
- Same Pinouts as 'AHC00
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)







SN74AHC132...RGY PACKAGE



SN54AHC132...FK PACKAGE

NC - No internal connection

### description/ordering information

The 'AHC132 devices are quadruple positive-NAND gates designed for 2-V to 5.5-V  $\rm V_{CC}$  operation.

These devices perform the Boolean function  $Y = \overline{A \bullet B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

#### **ORDERING INFORMATION**

TA	PACKA	GE <sup>†</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74AHC132RGYR	HA132
	PDIP – N	Tube	SN74AHC132N	SN74AHC132N
	SOIC - D	Tube	SN74AHC132D	AHC132
-40°C to 85°C	3010 - 15	Tape and reel	SN74AHC132DR	ATIC 132
-40°C to 85°C	SOP – NS	Tape and reel	SN74AHC132NSR	AHC132
	SSOP – DB	Tape and reel	SN74AHC132DBR	HA132
	TSSOP – PW	Tape and reel	SN74AHC132PWR	HA132
	TVSOP – DGV	Tape and reel	SN74AHC132DGVR	HA132
	CDIP – J	Tube	SNJ54AHC132J	SNJ54AHC132J
–55°C to 125°C	CFP – W	Tube	SNJ54AHC132W	SNJ54AHC132W
	LCCC – FK	Tube	SNJ54AHC132FK	SNJ54AHC132FK

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### SN54AHC132, SN74AHC132 QUADRUPLE POSITIVE-NAND GATES WITH SCHMITT-TRIGGER INPUTS

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### description/ordering information (continued)

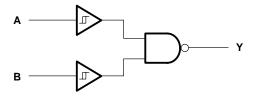
Each circuit functions as a NAND gate, but because of the Schmitt action, it has different input threshold levels for positive- and negative-going signals.

These circuits are temperature compensated and can be triggered from the slowest of input ramps and still give clean jitter-free output signals.

# FUNCTION TABLE (each gate)

INP	UTS	OUTPUT
Α	В	Y
Н	Н	L
L	X	Н
Х	L	Н

### logic diagram, each gate (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Output voltage range, V <sub>O</sub> (see Note 1)	
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	±25 mA
Continuous current through V <sub>CC</sub> or GND	±50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2): D package	86°C/W
(see Note 2): DB package	96°C/W
(see Note 2): DGV package	127°C/W
(see Note 2): N package	80°C/W
(see Note 2): NS package	76°C/W
(see Note 2): PW package	113°C/W
(see Note 3): RGY package	47°C/W
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The package thermal impedance is calculated in accordance with JESD 51-7.
- 3. The package thermal impedance is calculated in accordance with JESD 51-5.



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# recommended operating conditions (see Note 4)

			SN54A	HC132	SN74AI	HC132	UNIT	
			MIN	MAX	MIN	MAX	UNIT	
Vcc	Supply voltage		2	5.5	2	5.5	V	
VI	Input voltage		0	5.5	0	5.5	V	
Vo	Output voltage		0	Vcc	0	VCC	V	
		V <sub>CC</sub> = 2 V		-50		-50	μΑ	
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4	mA	
		$V_{CC} = 5 V \pm 0.5 V$	(0)	-8		-8	IIIA	
		V <sub>CC</sub> = 2 V	200	50		50	μΑ	
lOL	Low-level output current	$V_{CC}$ = 3.3 V $\pm$ 0.3 V	27	4		4	mA	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	IIIA	
TA	Operating free-air temperature		<b>–</b> 55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		T,	4 = 25°C		SN54AI	HC132	SN74AI	HC132	UNIT	
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP N	1AX	MIN	MAX	MIN	MAX	UNII	
V <sub>T+</sub>		3 V	1.2		2.2	1.2	2.2	1.2	2.2		
Positive-going		4.5 V	1.75	3	3.15	1.75	3.15	1.75	3.15	V	
input threshold voltage		5.5 V	2.15	3	3.85	2.15	3.85	2.15	3.85		
V <sub>T</sub> _		3 V	0.9		1.9	0.9	1.9	0.9	1.9		
Negative-going		4.5 V	1.35	2	2.75	1.35	2.75	1.35	2.75	V	
input threshold voltage		5.5 V	1.65	3	3.35	1.65	3.35	1.65	3.35		
AN/-		3 V	0.3		1.2	0.3	1.2	0.3	1.2		
$\Delta V_T$ Hysteresis ( $V_{T+} - V_{T-}$ )		4.5 V	0.4		1.4	0.4	1.4	0.4	1.4	V	
.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		5.5 V	0.5		1.6	0.5	1.6	0.5	1.6		
		2 V	1.9	2		1.9		1.9		V	
	I <sub>OH</sub> = -50 μA	3 V	2.9	3		2.9	ζ.	2.9			
Voн		4.5 V	4.4	4.5		4.4		4.4			
	I <sub>OH</sub> = -4 mA	3 V	2.58			2.48		2.48			
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8			
		2 V			0.1		0.1		0.1		
	I <sub>OL</sub> = 50 μA	3 V			0.1		0.1		0.1		
VOL		4.5 V			0.1		0.1		0.1	V	
	I <sub>OL</sub> = 4 mA	3 V		C	0.36		0.5		0.44		
	$I_{OL} = 8 \text{ mA}$	4.5 V		(	0.36		0.5		0.44		
lį	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V		±	±0.1		±1*		±1	μΑ	
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20		20	μΑ	
C <sub>i</sub>	$V_I = V_{CC}$ or GND	5 V		1.9	10				10	pF	

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested at  $V_{CC} = 0 \text{ V}$ .



## SN54AHC132, SN74AHC132 QUADRUPLE POSITIVE-NAND GATES WITH SCHMITT-TRIGGER INPUTS

SCLS365G - MAY 1997 - REVISED SEPTEMBER 2002

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			SN54AHC132		SN74AHC132		UNIT
PARAMETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
t <sub>PLH</sub>	A or B	~	C <sub>I</sub> = 15 pF		5.6*	11.9*	1*	<b>1</b> 4*	1	14	ns
<sup>t</sup> PHL	AUB	ī	CL = 15 pr		5.6*	11.9*	1*	14*	1	14	
<sup>t</sup> PLH	A or B		C <sub>I</sub> = 50 pF		7.6	15.4	P-10	17.5	1	17.5	ns
<sup>t</sup> PHL	AUB	r	CL = 50 pr		7.6	15.4	<b>V</b> 1	17.5	1	17.5	115

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	T <sub>A</sub> = 25°C		SN54AHC132		SN74AHC132		UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
<sup>t</sup> PLH	A or B	V	C 15 pF		3.9*	7.7*	1*	9*	1	9	no
t <sub>PHL</sub>	AUB	ī	C <sub>L</sub> = 15 pF		3.9*	7.7*	1*)	9*	1	9	ns
t <sub>PLH</sub>	A or B	V	C: - 50 pF		5.3	9.7	P10	11	1	11	20
<sup>t</sup> PHL	AUID	ī	C <sub>L</sub> = 50 pF		5.3	9.7	\Q_1	11	1	11	ns

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

### noise characteristics, $V_{CC} = 5 \text{ V}$ , $C_L = 50 \text{ pF}$ , $T_A = 25^{\circ}\text{C}$ (see Note 5)

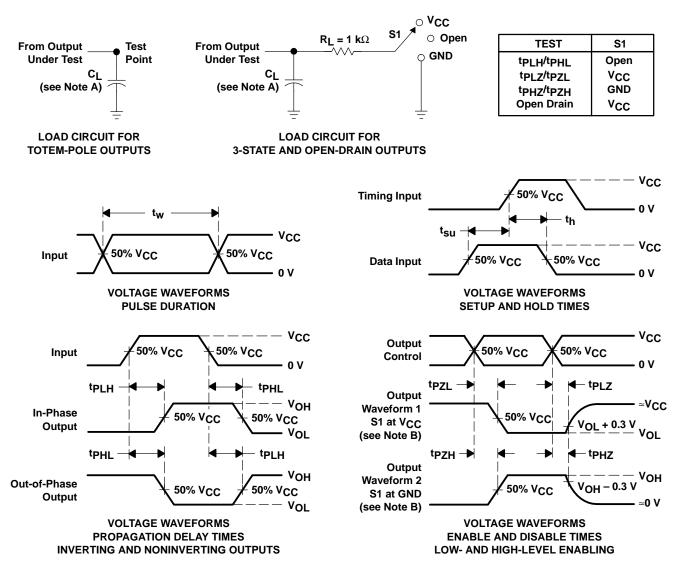
	PARAMETER	SN7	UNIT		
	PARAMETER	MIN	TYP	MAX	UNII
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.45	8.0	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.35	-0.8	٧
VOH(V)	Quiet output, minimum dynamic VOH		4.8		٧
V <sub>IH(D)</sub>	High-level dynamic input voltage	3.5			V
V <sub>IL(D)</sub>	Low-level dynamic input voltage			1.5	V

NOTE 5: Characteristics are for surface-mount packages only.

# operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	No load, f = 1 MHz	11	pF

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 3$  ns.  $t_f \leq 3$  ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms









### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74AHC132D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DBRE4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DBRG4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DGVR	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DGVRE4	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DGVRG4	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132N	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74AHC132NE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74AHC132NSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132NSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132NSRG4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132PWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132PWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AHC132RGYR	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74AHC132RGYRG4	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR



#### PACKAGE OPTION ADDENDUM

4-Jun-2007

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

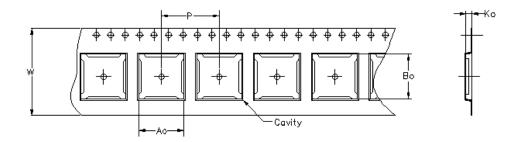
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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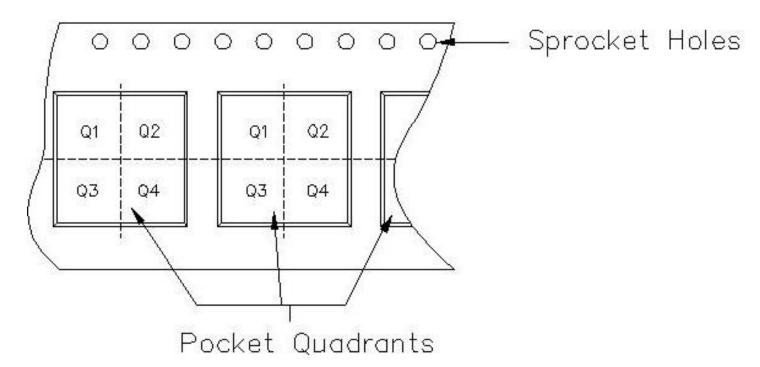
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Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao =	Dimension	designed	to	accommodate	the	component	width.				
Bo =	Dímension	designed	to	accommodate	the	component	length.				
Ko =	Dímension	designed	to	accommodate	the	component	thickness.				
W =	W = Overall width of the carrier tape.										
P =	Pitch betwe	en succes	ssiv	e cavity center	·s.						



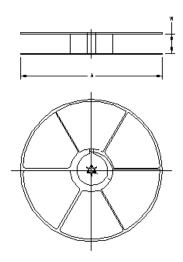
### TAPE AND REEL INFORMATION





tom 19-May-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC132DBR	DB	14	MLA	330	16	8.2	6.6	2.5	12	16	Q1
SN74AHC132DGVR	DGV	14	MLA	330	12	6.8	4.0	1.6	8	16	Q1
SN74AHC132DR	D	14	MLA	330	16	6.5	9.0	2.1	8	16	Q1
SN74AHC132NSR	NS	14	MLA	330	16	8.2	10.5	2.5	12	16	Q1
SN74AHC132PWR	PW	14	MLA	330	12	7.0	5.6	1.6	8	12	Q1
SN74AHC132RGYR	RGY	14	MLA	180	12	3.85	3.85	1.35	8	12	Q1



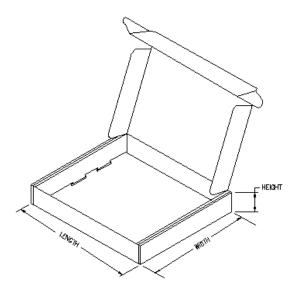
# TAPE AND REEL BOX INFORMATION

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
SN74AHC132DBR	DB	14	MLA	342.9	336.6	28.58
SN74AHC132DGVR	DGV	14	MLA	338.1	340.5	20.64
SN74AHC132DR	D	14	MLA	342.9	336.6	28.58
SN74AHC132NSR	NS	14	MLA	342.9	336.6	28.58
SN74AHC132PWR	PW	14	MLA	338.1	340.5	20.64
SN74AHC132RGYR	RGY	14	MLA	190.0	212.7	31.75





19-May-2007



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Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
RFID	www.ti-rfid.com	Telephony	www.ti.com/telephony
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